DS200ILP

Highly stabilized and precise fluxgate technology based current transducer, reengineered for cost sensitive, non-intrusive, isolated DC and AC current measurement applications up to 300A



Features

DANI/ENSE

Fluxgate, closed loop compensated technology with fixed excitation frequency and second harmonic zero flux detection for enhanced accuracy and stability

Industry standard 6.3 x 0.8mm faston connection

Plastic housing with $\phi 20.0mm$ aperture for insulated cables or bus bars

Industrial grade (non-instrumentation) components

Cost oriented high performance model

DC and AC (50/60Hz) current metering with +/-0.05% absolute accuracy

Applications:

- Gradient amplifiers for MRI devices
- Precision power supplies
- Batteries testing and evaluation systems
- Variable speed motor drives

Specification highlights	Symbol	Unit	Min	Тур.	Мах
Nominal primary AC current	IPN AC	Arms			200
Nominal primary DC current	IPN DC	А	-300		300
Measuring range	Îрм	А	-300		300
Primary / secondary ratio	n1 : n2		1:1000		1:1000
Linearity error	ε _L	%	-0.005		+0.005
Offset current (including earth field)	I _{OE}	%	-0.02		+0.02
DC-100Hz Overall accuracy @25°C(= ɛL + I _{OE})	acc8	%	-0.05		+0.05
AC Maximum gain error from 100Hz to 5kHz	8G	%			±0.5
Operating temperature range	Ta	°C	-40		+70
Power supply voltages	Uc	V	±14.25		±15.75

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Electrical specifications at Ta=23°C, supply voltage = ± 15V unless otherwise stated

Parameter	Symbol	Unit	Min	Тур.	Max	Comment
Nominal primary AC current	IPN AC	Arms		200		
Nominal primary DC current	IPN DC	А	-300		300	
Measuring range	Îрм	А	-300		300	
Overload capacity	Îol	А	-1500		1500	Non-measured, 100ms
Nominal secondary current	Isn	mA	-300		300	At nominal primary DC current
Primary / secondary ratio				1:1000		
Max. measuring resistance	Rм	Ω	0		20 10	@200A peak/DC @300A peak/DC
Linearity error	εL	%	-0.005		+0.005	% refers to ISN
Offset current (including earth field)	I _{OE}	%	-0.01		+0.01	% refers to ISN
Offset temperature coefficient	TCIOE	ppm/K	-3		+3	ppm refers to IsN
Bandwidth	f(-1dB)	kHz		1000		Small signal,
Gain error 100Hz – 5kHz 5kHz -100kHz 100kHz –1MHz	£G	%			0.50% 3.0% 50%	% of reading
Phase shift 100Hz – 5kHz 5kHz -100kHz 100kHz –1MHz	θ	o			0.2° 0.5° 20°	
Response time to a step cur- rent IPN	tr @ 90%	μs		1		di/dt = 100A/µs
Noise 0 - 100Hz 0 - 1kHz 0 - 10kHz 0 - 100kHz	noise	µA rms			0.2 2.0 15 30	Measured on secondary current
Fluxgate excitation frequency	fExc	kHz		15.6		
Power supply voltages	Uc	V	±14.25		±15.75	
Positive current consumption	lps	mA	30	32	33	Add Is (if Is is positive)
Negative current consumption	Ins	mA	-31	-33	-34	Add Is (if Is is negative)
Operating temperature range	Ta	°C	-40		+70	
Stability						
Offset stability over time		ppm/ month	-10		+10	ppm refers to IsN



Isolation specifications

Parameter	Unit	Value
Clearance	mm	9
Creepage distance	mm	10
Comparative tracking index (CTI)	V	> 600
Rms voltage for AC isolation test, 50/60 Hz, 1 min - Between primary and (secondary and shield) - Between secondary and shield	kV	5.7
Impulse withstand voltage (1.2/50µs)	kV	10.4
Rated rms isolation voltage reinforced isolation, overvoltage catego Pollution degree 2 according to - IEC 61010-1 - EN50780	ry III, V	300

Absolute maximum ratings

Parameter	Unit	Max	Comment
Primary	kA	3.0	Maximum 100ms
Power supply	V	±16.5	

Environmental and mechanical characteristics

Parameter	Unit	Min	Тур	Max	Comment
Operating temperature range	°C	-40		70	
Storage temperature range	°C	-40		85	
Relative humidity	%	20		80	Non-condensing
Mass	kg		0.17		
Connections	4 Industrial fastons 6.3 x 0.8mm				
Standards	EN 61326-1 EMC, EN 61010-1:2010 Safety				

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Mechanical Dimensions







(general tolerance 0.1mm unless otherwise stated)



DS200ILP connection



Positive current direction

Is identified by an arrow on the transducer body

Mounting instructions

• Base plate mounting

2holes φ5.5 2 x M5 screws